

YJ Planar Schottky Barrier Diode Die Specification

60V 10A, 87mil, Schottky barrier diode die based on silicon planar process
Part No.: PSB087M060AS-280A

Main Products Characteristics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

$$I_F = 10 \text{ A}$$
 $\leq 2\%$

Device Schematics and Outline Drawing

Die Thickness *

Die Size **

Top Metal Pad

Active Area

Top Metal